

# Differential Clock Buffer/Driver

#### **Features**

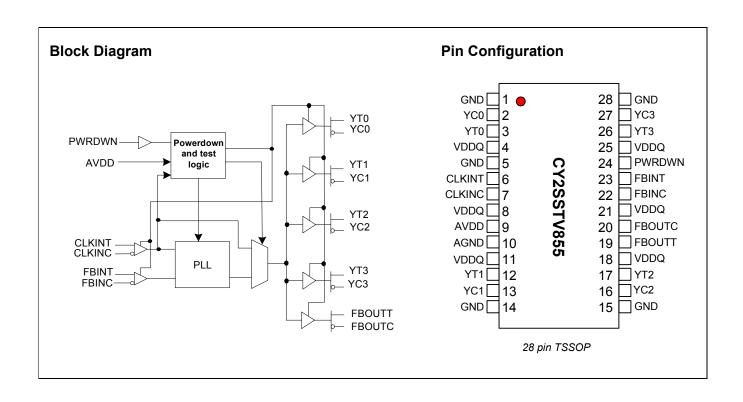
- Phase-locked loop (PLL) clock distribution for Double Data Rate Synchronous DRAM applications
- 1:5 differential outputs
- External feedback pins (FBINT, FBINC) are used to synchronize the outputs to the clock input
- SSCG: Spread Aware<sup>™</sup> for electromagnetic interference (EMI) reduction
- 28-pin TSSOP package
- Conform to JEDEC DDR specifications

### **Functional Description**

The CY2SSTV855 is a high-performance, very-low-skew, very-low-jitter zero-delay buffer that distributes a differential clock input pair (SSTL\_2) to four differential (SSTL\_2) pairs of clock outputs and one differential pair of feedback clock outputs. In support of low power requirements, when power-down is HIGH, the outputs switch in phase and frequency with the input clock. When power-down is LOW, all outputs are disabled to a high-impedance state and the PLL is shut down.

The device supports a low-frequency power-down mode. When the input is < 20 MHz, the PLL is disabled and the outputs are put in the Hi-Z state. When the input frequency is > 20 MHz, the PLL and outputs are enabled.

When AVDD is tied to ground, the PLL is turned off and bypassed with the input reference clock gated to the outputs. The Cypress CY2SSTV855 is Spread Aware and supports tracking of Spread Spectrum clock inputs to reduce EMI





#### Pin Definition[1, 2]

Pin	Name	I/O	Description
6	CLKINT	I	True Clock Input. Low Voltage Differential True Clock Input.
7	CLKINC	I	Complementary Clock Input. Low Voltage Differential Complementary Clock Input.
22	FBINC	I	Feedback Complementary Clock Input. Differential Input Connect to FBOUTC for accessing the PLL.
23	FBINT	I	Feedback True Clock Input. Differential Input Connect to FBOUTT for accessing the PLL.
3,12,17,26	YT(0:3)	0	True Clock Outputs. Differential Outputs.
2,13,16,27	YC(0:3)	0	Complementary Clock Outputs. Differential Outputs.
19	FBOUTT	0	<b>Feedback True Clock Output</b> . Differential Outputs. Connect to FBINT for normal operation. A bypass delay capacitor at this output will control Input Reference/Output Clocks phase relationships.
20	FBOUTC	0	<b>Feedback Complementary Clock Output</b> . Differential Outputs. Connect to FBINC for normal operation. A bypass delay capacitor at this output will control Input Reference/Output Clocks phase relationships.
24	PWRDWN	I	Control input to turn device in the power-down mode.
4,8,11,18,21,25	VDDQ		2.5V Power Supply for Output Clock Buffers.2.5V Nominal.
9	AVDD		2.5V Power Supply for PLL. 2.5V Nominal.
1,5,14,15,28	GND		Ground
10	AGND		Analog Ground. 2.5V Analog Ground.

## **Zero-delay Buffer**

When used as a zero-delay buffer the CY2SSTV855 will likely be in a nested clock tree application. For these applications the CY2SSTV855 offers a differential clock input pair as a PLL reference. The CY2SSTV855 then can lock onto the reference and translate with near zero delay to low-skew outputs. For normal operation, the external feedback differential input, FBINT/C, is connected to the feedback output, FBOUTT/C. By connecting the feedback output to the feedback input the

propagation delay through the device is eliminated. The PLL works to align the output edge with the input reference edge thus producing a near zero delay. The reference frequency affects the static phase offset of the PLL and thus the relative delay between the inputs and outputs.

When AVDD is strapped LOW, the PLL is turned off and bypassed for test purposes.

#### **Function Table**

	Inputs			Outputs				
AVDD	PWRDWN	CLKINT	CLKINC	YT(0:3)	YC(0:3)	FBOUTT	FBOUTC	PLL
GND	Н	L	Н	L	Н	L	Н	BYPASSED/OFF
GND	Н	Н	L	Н	L	Н	L	BYPASSED/OFF
2.5V	Н	L	Н	L	Н	L	Н	On
2.5V	Н	Н	L	Н	L	Н	L	On
2.5V	Х	< 20 MHz	< 20 MHz	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Off

#### Notes

Document #: 38-07459 Rev. \*D Page 2 of 7

<sup>1.</sup> PU = internal pull-up.

<sup>2.</sup> A bypass capacitor (0.1µF) should be placed as close as possible to each positive power pin (< 0.2"). If these bypass capacitors are not close to the pins their high frequency filtering characteristic will be cancelled by the lead inductance of the traces.</p>



## **Differential Parameter Measurement Information**

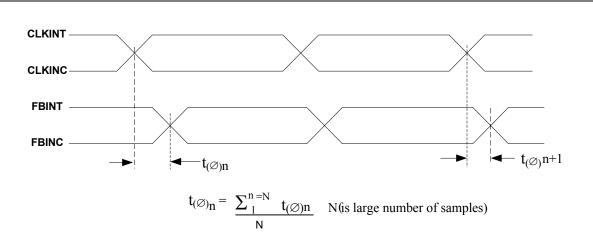


Figure 1. Static Phase Offset

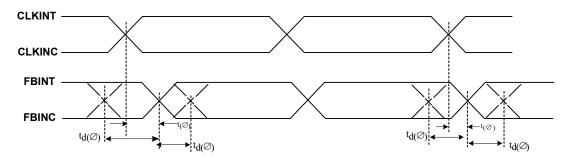


Figure 2. Dynamic Phase Offset

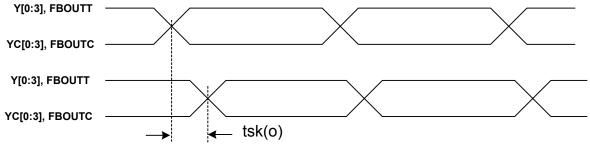


Figure 3. Output Skew



## **Differential Parameter Measurement Information** (continued)

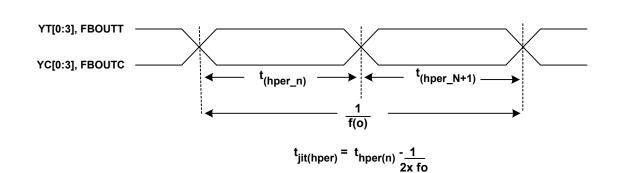


Figure 4. Half-period Jitter

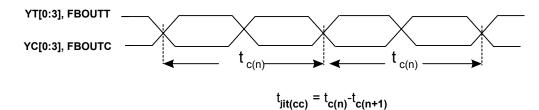


Figure 5. Cycle-to-cycle Jitter

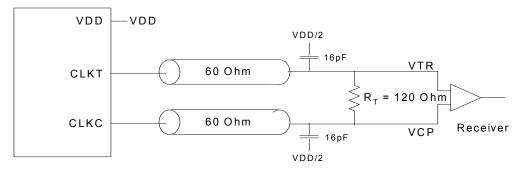


Figure 6. Differential Signal Using Direct Termination Resistor



## Absolute Maximum Conditions[3]

Input Voltage Relative to V <sub>SS</sub> :	V <sub>SS</sub> – 0.3V
Input Voltage Relative to $V_{DDQ}$ or $AV_{DD}$ :	V <sub>DD</sub> + 0.3V
Storage Temperature:	65°C to + 150°C
Operating Temperature:	40°C to +85°C
Maximum Power Supply:	3.5V

This device contains circuitry to protect the inputs against damage due to high static voltages or electric field; however,

precautions should be taken to avoid application of any voltage higher than the maximum rated voltages to this circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range:

 $V_{SS} < (V_{in} \text{ or } V_{out}) < V_{DD}.$ 

Unused inputs must always be tied to an appropriate logic voltage level (either  $V_{SS}$  or  $V_{DD}$ ).

## DC Electrical Specifications (AV<sub>DD</sub> = $V_{DDO}$ = 2.5V ± 5%, $T_A$ = -40°C to +85°C)<sup>[4]</sup>

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
$V_{ID}$	Differential Input Voltage <sup>[5]</sup>	CLKINT, FBINT	0.36		V <sub>DDQ</sub> + 0.6	V
V <sub>IX</sub>	Differential Input Crossing Voltage <sup>[6]</sup>	CLKTIN, FBINT	(V <sub>DDQ</sub> /2) – 0.2	V <sub>DDQ</sub> /2	$(V_{DDQ}/2) + 0.2$	V
I <sub>IN</sub>	Input Current	$V_{IN}$ = 0V or $V_{IN}$ = $V_{DDQ}$ , CLKINT, FBINT	-10	-	10	μA
I <sub>OL</sub>	Output Low Current	V <sub>DDQ</sub> = 2.375V, V <sub>OUT</sub> = 1.2V	26	35	-	mA
I <sub>OH</sub>	Output High Current	V <sub>DDQ</sub> = 2.375V, V <sub>OUT</sub> = 1V	-18	-32	_	mA
V <sub>OL</sub>	Output Low Voltage	V <sub>DDQ</sub> = 2.375V, I <sub>OL</sub> = 12 mA		-	0.6	V
V <sub>OH</sub>	Output High Voltage	$V_{\rm DDQ}$ = 2.375V, $I_{\rm OH}$ = -12 mA	1.7	-	_	V
V <sub>OUT</sub>	Output Voltage Swing <sup>[7]</sup>		1.1	-	V <sub>DDQ</sub> – 0.4	V
V <sub>OC</sub>	Output Crossing Voltage <sup>[8]</sup>		$(V_{DDQ}/2) - 0.2$	V <sub>DDQ</sub> /2	$(V_{DDQ}/2) + 0.2$	V
I <sub>OZ</sub>	High-Impedance Output Current	$V_O = GND \text{ or } V_O = V_{DDQ}$	-10		10	μA
I <sub>DDQ</sub>	Dynamic Supply Current <sup>[9]</sup>	V <sub>DDQ</sub> = 170 MHz	_	235	300	mA
I <sub>DD</sub>	PLL Supply Current	AV <sub>DD</sub> only	_	9	12	mA
Cin	Input Pin Capacitance		_	4	_	pF

## AC Electrical Specifications (AV<sub>DD</sub> = $V_{DDQ}$ = 2.5V±5%, $T_A$ = -40°C to +85°C)<sup>[10, 11]</sup>

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
f <sub>CLK</sub>	Operating Clock Frequency	$AV_{DD} = 2.5V \pm 0.2V$	60		170	MHz
t <sub>DC</sub>	Input Clock Duty Cycle <sup>[12]</sup>		40		60	%
t <sub>LOCK</sub>	Maximum PLL lock Time				100	μs
t <sub>SL(O)</sub>	Output Clocks Slew Rate	20% to 80% of VOD	1		2	V/ns
$t_{PZL}, t_{PZH}$	Output Enable Time (all outputs) <sup>[13]</sup>			30		ns
$t_{PLZ}$ , $t_{PHZ}$	Output Disable Time (all outputs) <sup>[13]</sup>			10		ns
t <sub>CCJ</sub>	Cycle to Cycle Jitter	f > 66 MHz	-100		100	ps
t <sub>JITT(H-PER)</sub>	Half-period jitter	f > 66 MHz	-100		100	ps
t <sub>PLH</sub>	Low-to-High Propagation Delay, CLKINT to YT[0:3]		1.5	3.5	6	ns

#### Notes:

- 3. Multiple Supplies: The voltage on any input or I/O pin cannot exceed the power pin during power-up. Power supply sequencing is NOT required.
- 4. Unused inputs must be held HIGH or LOW to prevent them from floating.
- 5. Differential input signal voltage specifies the differential voltage |VTR VCP| required for switching, where VTR is the true input level and VCP is the complementary input level.
- 6. Differential cross-point input voltage is expected to track V<sub>DDQ</sub> and is the voltage at which the differential signals must be crossing.
- 7. For load conditions see Figure 6.
- 8. The value of  $V_{OC}$  is expected to be |VTR + VCP|/2. In case of each clock directly terminated by a  $120\Omega$  resistor. See Figure 6.
- 9. All outputs switching loaded with 16 pF in  $60\Omega$  environment. See *Figure 6*.
- 10. Parameters are guaranteed by design and characterization. Not 100% tested in production.
- 11. PLL is capable of meeting the specified parameters while supporting SSC synthesizers with modulation frequency between 30 kHz and 33.3 kHz with a downspread of -0.5%
- 12. While the pulse skew is almost constant over frequency, the duty cycle error increases at higher frequencies. This is due to the formula: duty cycle = t<sub>WH</sub>/t<sub>C</sub>, where the cycle time (t<sub>C</sub>) decreases as the frequency goes up.
- 13. Refers to transition of non-inverting output.
- 14. All differential input and output terminals are terminated with 120Ω/16 pF as shown in Figure 6.



# AC Electrical Specifications (AV $_{DD}$ = V $_{DDQ}$ = 2.5V±5%, T $_{A}$ = -40°C to +85°C)[10, 11] (continued)

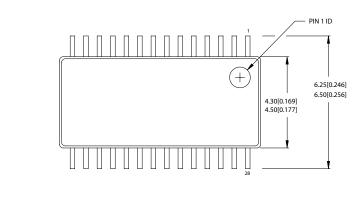
Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
t <sub>PHL</sub>	High-to-Low Propagation Delay, CLKINT to YT[0:3]		1.5	3.5	6	ns
t <sub>SK(0)</sub>	Any Output to Any Output Skew <sup>[14]</sup>		_	_	100	ps
$t_{(\emptyset)}$	Static Phase Offset <sup>[14]</sup>		-150	_	150	ps
$t_{D(\emptyset)}$	Dynamic Phase Offset	f > 66 MHz	-150	_	150	ps

#### **Ordering Information**

Part Number	Package Type	Product Flow
CY2SSTV855ZC	28-pin TSSOP	Commercial, 0° to 70°C
CY2SSTV855ZCT	28-pin TSSOP – Tape and Reel	Commercial, 0° to 70°C
CY2SSTV855ZI	28-pin TSSOP	Industrial, –40° to 85°C
CY2SSTV855ZIT	28-pin TSSOP – Tape and Reel	Industrial,–40° to 85°C

### **Package Drawing and Dimensions**

#### 28-Lead Thin Shrunk Small Outline Package (4.40-mm Body) Z28.173

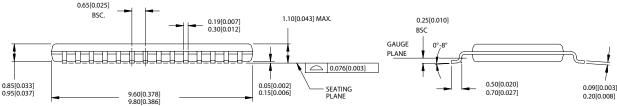


DIMENSIONS IN MM[INCHES] MIN. MAX.

REFERENCE JEDEC MO-153

PACKAGE WEIGHT 0.16 gms

PART #		
Z28.173	STANDARD PKG.	
ZZ28.173	LEAD FREE PKG.	



51-85120-\*A

Spread Aware is a trademark of Cypress Semiconductor. All product and company names mentioned in this document may be the trademarks of their respective holders.



# **Document History Page**

REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	117544	09/09/02	HWT	New data sheet
*A	122934	12/18/02	RBI	Add power up requirements to maximum ratings information
*B	124087	04/23/03	RGL	Changed the package drawing and dimension from Z28 to Z29 Corrected the block diagram Changed the Output Enable/Disable time from 3/3 to 30/10 ns Eliminated Dynamic Phase Offset spec. Changed the Phase Error Jitter spec. from ±50 to ±150 ps
*C	215389	See ECN	RGL	Added an Industrial Grade Devices (temp from –40°C to 85).
*D	224444	See ECN	RGL	Removed "PRELIMINARY"